			<u> </u>	Г		<u></u>
Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	4	(("5451548") or ("5474851") or ("5897812") or ("4377613")).PN.	USPAT	OR	OFF	2006/09/11 16:41
S2	237	427/255.23.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/11 16:32
S3	714	427/255.28.ccls.	US-PGPUB; USPAT; DERWENT;	OR	ON	2006/09/11 16:32
•			IBM_TDB			
S4	2496	427/248.1.ccls.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/11 16:40
S5	8	remington-michael-p\$.in.	US-PGPUB;	OR	ON	2006/09/11 16:33
			USPAT; DERWENT; IBM_TDB			
S6	22	strickler-david-a.in.	US-PGPUB;	OR	ON	2006/09/11 16:33
		į	USPAT; DERWENT; IBM_TDB			·.
S7	16	varanasi-srikanth.in.	US-PGPUB; USPAT; DERWENT;	OR	ON	2006/09/11 16:33
			IBM_TDB			
S8	0	S2 and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:40
S9	4.	S3 and (gallium oxide)	US-PGPUB;	ADJ	ON	2006/09/11 16:41
			USPAT; DERWENT; IBM_TDB			
S10	8	S4 and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:41
S11	26	(chemical vapor deposition) same (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/12 07:48
S12	2769	(gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:45

			· · · · · · · · · · · · · · · · · · ·		·		
S13		· 58	(chemical vapor deposit\$3 or \$cvd or vapor deposit\$3) same (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:58
S14			S13 and (ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:47
S15		98	(ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate) and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 16:47
S16		98	(ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate) and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/12 07:52
S17		8	S16 and (\$2cvd or vapor deposition)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:35
S18		935	(chemical vapor deposit\$3 or \$2cvd or vapor deposit\$3) same (gallium with oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:37
S20	:	74	(chemical vapor deposit\$3 or \$2cvd or vapor deposit\$3) same (gallium with oxide) and (ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:42
S21		6	("4187336" "4331737" "4371587" "4595634").PN. OR ("5474851").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/11 17:38
S22		74	(chemical vapor deposit\$3 or \$2cvd or vapor deposit\$3) same ((gallium with oxide) or ("ga.sub.2o.sub.3")) and (ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:44
S23	1.	80	(chemical vapor deposit\$3 or \$2cvd or vapor deposit\$3) same ((gallium with oxide) or ("ga.sub.2o.sub.3")) and (ester)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/11 17:44
S24		54	S23 not S22	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON .	2006/09/11 17:44

S25	2	("4,187,336").PN.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	OFF	2006/09/12 07:07
S26	46	gordon-roy-g.in.	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:22
S27	18	S26 and gallium	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:26
S29	71	(((gallium with oxide) ("ga.sub.2o. sub.3") gallia) with (film layer)) same (\$2cvd (chemical adj vapor adj deposit\$2)) same (glass with (substrate ribbon plate wafer))	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:49
S31	12557	(gallium with oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:33
S32	17	S31 with (film layer) same (\$2cvd (chemical adj vapor adj deposit\$2)) same (glass with (substrate ribbon plate wafer))	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:48
S33	197534	(aluminum with oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:34
S34	310	S33 with (film layer) same (\$2cvd (chemical adj vapor adj deposit\$2)) same (glass with (substrate ribbon plate wafer))	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:44
S35	1	S34 and (aluminum adj trichloride)	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:35
S37	17	S31 with (film layer coating) same (\$2cvd (chemical adj vapor adj deposit\$2)) same (glass with (substrate ribbon plate wafer))	US-PGPUB; USPAT; DERWENT; IBM_TDB	OR	ON	2006/09/12 07:48
S38	4	(chemical vapor deposition) same (gallium oxide)	EPO; JPO; DERWENT	ADJ	ON	2006/09/12 07:49
S39	3	(((gallium with oxide) ("ga.sub.2o. sub.3") gallia) with (film layer)) same (\$2cvd (chemical adj vapor adj deposit\$2)) same (glass with (substrate ribbon plate wafer))	USOCR; EPO; JPO	OR	ON	2006/09/12 07:50

S40	5	(ethyl acetate or isobutyl acetate or n-butyl acetate or t-butyl acetate or tert-butyl acetate or ethyl formate) and (gallium chloride) and (gallium oxide)	US-PGPUB; USPAT; DERWENT; IBM_TDB	ADJ	ON	2006/09/12 07:53
S41	12	("5389401").URPN.	USPAT	OR	ON	2006/09/12 08:28
S42	6	("4187336" "4331737" "4371587" "4595634").PN. OR ("5474851").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/09/12 08:35
S44	12	("4187336" "4331737" "4371587" "4595634").PN. OR ("5474851").URPN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	* · · · · · · · · · · · · · · · · · · ·	*	2006/09/12 08:35